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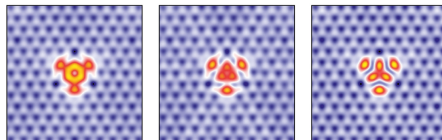
Transition Metals and Silicon

Magnetic Properties of Thin Films, Impurities, and Heusler Alloys on the Atomic Scale

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**Magnetic Properties of Thin Films,
Impurities, and Heusler Alloys
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Contents

	Page
1 Introduction	9
2 Methodology	15
2.1 The electronic structure	16
2.2 Density functional theory	19
2.3 Scanning tunneling microscopy	38
2.4 Ballistic quantum transport	42
3 Transition metal silicide thin films on Si(111)	47
3.1 Introduction and overview	48
3.2 Properties of bulk Si and of the Si(111) surface	49
3.3 Bulk properties of 3d transition metal monosilicides	59
3.4 The effect of epitaxial strain	74
3.5 Correlation effects in MnSi and FeSi	84
3.6 Growth mode and atomic structure of MnSi/Si(111)	86
3.7 Magnetic properties of MnSi/Si(111) thin films	107
3.8 Interface and surface properties of Mn ₅ Si ₃ /Si(111)	112
4 Transition metal impurities in Si	121
4.1 Introduction and overview	122
4.2 The H/Si(111) and H/GaAs(110) surfaces and surface states	123
4.3 Transition metal impurities in bulk Si	127
4.4 Wave function imaging of H/Si(111) subsurface impurities	137
4.5 Two-dimensional subsurface impurity layers and clusters	150
4.6 Subsurface doping with organic molecules	158
5 Magnetic tunnel junctions with Heusler electrodes	167
5.1 Introduction and overview	168
5.2 Properties of Co ₂ MnSi and MgO	169
5.3 Phonon influence on the half-metallic gap	174
5.4 Magnetic tunnel junctions	177
6 Summary and Outlook	193
A Computational details	199



List of Figures	205
List of Tables	209
List of Abbreviations	211
References	213
Danksagungen	231